# NSN 5962-01-413-5235

Memory Microcircuit - Page 1 of 1



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## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## Features Provided:

Low power

## **Inclosure Material:**

Ceramic

### Inclosure Configuration:

Leaded chip carrier

#### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

#### **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

#### **Time Rating Per Chacteristic:**

20.00 nanoseconds af output megawatts

#### Memory Device Type:

Ram

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

32 leadless

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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